| Ref<br>#  | Hits | Search Query  | DBs   | Default<br>Operator | Plurals | Time Stamp       |
|-----------|------|---|---|---------------------|---------|------------------|
| L1        | 4864 | 257/758   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR                  | ON      | 2005/06/21 03:05 |
| S1        | 39   | (semiconductor or die or chip or IC) and dummy near via and dummy near (wirings or conductive or pattern) | USPAT   | OR                  | ON      | 2004/12/23 14:13 |
| S2        | 46   | (semiconductor or die or chip or IC) and dummy near via and dummy near (wirings or conductive or pattern) | USPAT;<br>JPO   | OR                  | ON      | 2004/12/22 01:10 |
| S3        | 0    | "11350284"  | JPO   | OR                  | ON      | 2004/12/22 01:11 |
| S4        | 0    | "110350284"   | JPO   | OR                  | ON      | 2004/12/22 01:11 |
| S5        | 0    | "11350284"  | JPO   | OR                  | ON      | 2004/12/22 01:11 |
| S6        | 1867 | dielectric near constant with (silicon near dioxide)  | USPAT   | OR                  | OFF     | 2004/12/23 17:44 |
| <b>S7</b> | 1887 | dielectric near constant with (silicon near nitride)  | USPAT   | OR                  | OFF     | 2004/12/22 02:06 |
| S8        | 358  | dielectric near constant with (SOG)   | USPAT   | OR                  | OFF     | 2004/12/22 02:06 |
| S9        | 6167 | dimension with via  | USPAT   | OR                  | ON      | 2004/12/22 13:38 |
| S10       | 7164 | (dimension or (cross-sectional or cross near secional) near area) with via                                | USPAT   | OR                  | ON      | 2004/12/22 13:39 |
| S11       | 1065 | ((cross-sectional or cross near secional) near area) with via   | USPAT   | OR                  | ON      | 2004/12/22 13:40 |
| S12       | 7    | S11 and ((cross-sectional or cross near secional) near area) with via with normal                         | USPAT   | OR                  | ON      | 2004/12/22 13:41 |
| S13       | 0    | ( chip or die) and ((cross-sectional or cross near secional) near area) with via with normal              | USPAT   | OR                  | ON      | 2004/12/22 13:41 |
| S14       | 219  | ( chip or die) and ((cross-sectional or cross near secional) near area) with via                          | USPAT   | OR                  | ON      | 2004/12/22 14:09 |
| S15       | 0    | S14 and via with "microns.sub2"   | USPAT   | OR                  | ON      | 2004/12/22 14:21 |
| S16       | 0    | S14 and via with "\$.sub2"  | USPAT   | OR                  | ON      | 2004/12/22 13:50 |
| S17       | 0    | S14 and via with "sub2"   | USPAT   | OR                  | ON      | 2004/12/22 13:50 |
| S18       | 0    | S14 and via with "-2"   | USPAT   | OR                  | ON      | 2004/12/22 13:50 |

| S19 | 6      | "5,023,850".pn. or "4,551,857".   | USPAT   | OB      | ON   | 2004/12/22 12:55 |
|-----|--------|---|---|---------|------|------------------|
| 319 |        | pn. or "4,320,756".pn. or "5,934,<br>226".pn. or "4,905,406".pn. or "5,<br>901,666".pn. | USPAT   | OR      | ON   | 2004/12/22 13:55 |
| S20 | 42     | S14 and diameter with via   | USPAT   | OR      | ON   | 2004/12/22 14:10 |
| S21 | 0      | S14 and via with "microns.sup2"   | USPAT   | OR      | ON   | 2004/12/22 14:24 |
| S22 | 0      | S14 and via with ".sup2"  | USPAT   | OR      | ON   | 2004/12/22 14:21 |
| S23 | 0      | S14 and via with "-2"   | USPAT   | OR      | ON   | 2004/12/22 14:21 |
| S24 | 0      | S14 and via with ".sup."  | USPAT   | OR      | ON   | 2004/12/22 14:21 |
| S25 | 0      | S11 and via with "microns.sup2"   | USPAT   | OR      | ON   | 2004/12/22 14:22 |
| S26 | 0      | S11 and via with ".sup2"  | USPAT   | OR      | ON   | 2004/12/22 14:22 |
| S27 | 0      | S11 and via same ".sup2"  | USPAT   | OR      | ON   | 2004/12/22 14:22 |
| S28 | 0      | S11 and vias same ".sup2"   | USPAT   | OR      | ON   | 2004/12/22 14:22 |
| S29 | 0      | ".sup2"   | USPAT   | OR      | ON   | 2004/12/22 14:22 |
| S30 | 0      | ".sup2"   | USPAT   | OR      | ON   | 2004/12/22 14:24 |
| S31 | 0      | "mu.m.sup2"   | USPAT   | OR      | ON   | 2004/12/22 14:24 |
| S32 | . 0    | "mu.m.sup."   | USPAT   | OR      | ON   | 2004/12/22 14:24 |
| S33 | 296570 | "mu.m"  | USPAT   | OR      | ON   | 2004/12/22 14:24 |
| S34 | 35     | S14 and via with (microns or "mu. m")   | USPAT   | OR      | ON   | 2004/12/22 19:36 |
| S35 | 5041   | 257/758   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR      | ON . | 2004/12/22 19:57 |
| S36 | 3612   | 257/774   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR      | ON   | 2004/12/22 20:06 |
| S37 | 1164   | 257/775   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR      | ON   | 2004/12/22 20:18 |
| S38 | 1262   | 257/776   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR<br>· | ON   | 2004/12/22 22:11 |

| S39 | 2755 | 257/700  | US-PGPUB;  | OR | ON  | 2004/12/22 22:11 |
|-----|------|--|--|----|-----|------------------|
|     | ·    |  | USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |    |     |                  |
| S40 | 14   | (semiconductor or die or chip or IC) and dummy near (wirings or conductive or pattern) with SOG  | USPAT  | OR | ON  | 2004/12/23 18:44 |
| S41 | 4    | (semiconductor or die or chip or IC) and dummy near (wirings or conductive or pattern) with ground near (layer or film or plane)                             | USPAT  | OR | ON  | 2004/12/23 17:51 |
| S42 | 18   | (semiconductor or die or chip or IC) and dummy near (wirings or conductive or pattern or layer or film) with SOG   | USPAT  | OR | ON  | 2004/12/23 15:07 |
| S43 | 1132 | dielectric near constant with (polyimide)  | USPAT  | OR | OFF | 2004/12/23 17:44 |
| S44 |      | (semiconductor or die or chip or IC) and dummy near (wirings or conductive or pattern) with (xerogel or BCB)   | USPAT  | OR | ON  | 2004/12/23 17:51 |
| S45 | 8    | (semiconductor or die or chip or IC) and dummy near (wirings or conductive or pattern) and (xerogel or BCB) with (insulat\$3 or dielectric)                  | USPAT  | OR | ON  | 2004/12/23 17:52 |
| S46 | 16   | (semiconductor or die or chip or IC) and dummy near (wirings or conductive or pattern or film or layer) and (xerogel or BCB) with (insulat\$3 or dielectric) | USPAT  | OR | ON  | 2004/12/23 18:01 |
| S47 | 2    | "09315682"   | JPO  | OR | ON  | 2004/12/23 18:02 |
| S48 | 2    | "10037673"   | JPO  | OR | ON  | 2004/12/23 18:02 |
| S49 | 0    | (semiconductor or die or chip or IC) and dummy near (vias or contact near hole) with slit  | USPAT  | OR | ON  | 2004/12/23 18:45 |
| S50 | 2    | (semiconductor or die or chip or IC) and dummy with (vias or contact near hole) with slit  | USPAT  | OR | ON  | 2004/12/23 18:45 |
| S51 | 1    | "6319809".pn.  | USPAT  | OR | OFF | 2005/06/20 13:04 |
| S52 | 5    | 257/758 and (dummies or<br>dummy) and coplanar with<br>(interconnect or wiring)  | USPAT  | OR | ON  | 2005/06/20 14:00 |
| S53 | 49   | 257/758 and coplanar with (interconnect or wiring)   | USPAT  | OR | ON  | 2005/06/20 14:00 |

| 654 | 7 20- |  | T   | T  | Ι      | T                |
|-----|-------|--|---|----|--------|------------------|
| S54 | 305   | damascene and (dummy or<br>dummies) and (dielectric or<br>insulat\$3) with (SOG or glass or<br>silicon)                    | USPAT   | OR | ON     | 2005/06/20 15:27 |
| S55 |       | damascene and (dummy or<br>dummies) near (via or hole) and<br>(dielectric or insulat\$3) with (SOG<br>or glass or silicon) | USPAT   | OR | ON<br> | 2005/06/20 14:26 |
| S56 | 283   | S54 not S55  | USPAT   | OR | ON     | 2005/06/20 14:32 |
| S57 | 29    | damascene and (dummy or dummies) near (via or hole)  | USPAT   | OR | ON     | 2005/06/20 15:27 |
| S58 | 83    | damascene and (dummy or dummies) with (via or hole)  | USPAT   | OR | ON     | 2005/06/20 19:41 |
| S59 | 818   | dielectric near constant with ("BCB" or "HSQ" or "SiOF")   | USPAT   | OR | ON     | 2005/06/20 16:32 |
| S60 | 329   | dielectric near constant with ("BCB" )   | USPAT   | OR | ON     | 2005/06/20 17:07 |
| S61 | 82    | damasc\$3 and (dummy or<br>dummies) with (via or hole)   | USPAT   | OR | ON     | 2005/06/20 16:42 |
| S62 | 366   | damasc\$3 and (dummy or dummies)   | USPAT   | OR | ON     | 2005/06/20 20:30 |
| S63 | 57    | dielectric near constant with (helium )  | USPAT   | OR | ON     | 2005/06/20 18:57 |
| S64 | 1     | "5948928".PN.  | USPAT;<br>USOCR   | OR | OFF    | 2005/06/20 17:29 |
| S65 | 1     | "20020160599"  | US-PGPUB;<br>USPAT                                      | OR | ON     | 2005/06/20 18:57 |
| S66 | 47    | damascene and (dummy or<br>dummies) and (dielectric or<br>insulat\$3) with ("SOG" or parylene<br>or xerogel)               | USPAT   | OR | ON     | 2005/06/20 20:30 |
| S67 | 361   | damascene and (dummy or dummies)   | USPAT   | OR | ON     | 2005/06/20 20:30 |
| S68 | 501   | damasc\$3 and (dummy or dummies)   | US-PGPUB;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON     | 2005/06/20 21:14 |
| S69 | 366   | damasc\$3 and (dummy or dummies)   | USPAT   | OR | ON     | 2005/06/20 21:14 |
| S70 | 1     | "20050035457"  | US-PGPUB;<br>USPAT;<br>JPO                              | OR | OFF    | 2005/06/21 00:27 |
| S71 | 1     | "20050035457" and dummy with "10" with times   | US-PGPUB;<br>USPAT;<br>JPO                              | OR | OFF    | 2005/06/20 21:33 |

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|-----------|-------|---|----------------------------|-----|-----|------------------|
| S72       | 1     | "6717268".pn. or "2001429552".<br>pn.   | US-PGPUB;<br>USPAT;<br>JPO | OR  | OFF | 2005/06/20 21:34 |
| S73       | 1     | "6717268".pn. or "2001429552".<br>pn.   | US-PGPUB;<br>USPAT;<br>JPO | OR  | ON  | 2005/06/20 21:34 |
| S74       | . 1   | "6717268".pn. or "2001429552".<br>pn. and dummy   | US-PGPUB;<br>USPAT;<br>JPO | OR  | ON  | 2005/06/20 21:35 |
| S75       | . 1   | "6717268".pn. or "2001429552".<br>pn. and dummy   | US-PGPUB;<br>USPAT;<br>JPO | OR  | ON  | 2005/06/20 21:37 |
| S76       | 14382 | ( dummy or dummies) and (semiconductor or die or dice or chip or IC)  | USPAT                      | OR  | ON  | 2005/06/20 21:38 |
| S77       | 2865  | ( dummy or dummies) with (via ro<br>hole or plug or interconect\$3 or<br>pattern) and (semiconductor or die<br>or dice or chip or IC) | USPAT                      | OR  | ON  | 2005/06/20 21:38 |
| S78       | 1474  | ( dummy or dummies) with (via ro<br>hole ) and (semiconductor or die<br>or dice or chip or IC)  | USPAT                      | OR  | ON  | 2005/06/20 21:56 |
| S79       | 97    | ( dummy or dummies) with (via ro<br>hole ) and (semiconductor or die<br>or dice or chip or IC) and cap                                | USPAT                      | OR  | ON  | 2005/06/20 22:04 |
| S80       | 90    | ( dummy or dummies) with (via ro hole ) and (semiconductor or die or dice or chip or IC) and 257/758                                  | USPAT                      | OR  | ON  | 2005/06/20 22:18 |
| S81       | 775   | ( dummy or dummies) with (via ro<br>hole ) and (semiconductor or die<br>or dice or chip or IC) and<br>(multi\$5)                      | USPAT                      | OR  | ON  | 2005/06/20 22:18 |
| S82       | 1     | "20050035457" and vias with cap   | US-PGPUB;<br>USPAT;<br>JPO | OR  | ON  | 2005/06/21 00:27 |
| S83       | 368   | damasc\$3 and (dummy or dummies)  | USPAT                      | OR. | ON  | 2005/06/21 01:26 |
| S84       | 124   | dual near damasc\$3 and (dummy or dummies)  | USPAT                      | OR  | ON  | 2005/06/21 01:56 |
| S85       | 0     | (dummy or dummies) with diameter with "10" near times with (vias or via or hole)  | USPAT                      | OR  | ON  | 2005/06/21 03:04 |